

# **Complementary Silicon Plastic Power Transistors**

# BD241C (NPN), BD242B (PNP), **BD242C (PNP)**

Designed for use in general purpose amplifier and switching applications.

#### **Features**

- High Current Gain Bandwidth Product
- Compact TO-220 AB Package
- Epoxy Meets UL94 V-0 @ 0.125 in
- These Devices are Pb-Free and are RoHS Compliant\*

### **MAXIMUM RATINGS**

Rating	Symbol	BD242B	BD241C BD242C	Unit
Collector-Emitter Voltage	$V_{CEO}$	80	100	Vdc
Collector-Emitter Voltage	V <sub>CES</sub>	90	115	Vdc
Emitter-Base Voltage	V <sub>EB</sub>	5.	.0	Vdc
Collector Current -Continuous	I <sub>C</sub>	3.	.0	Adc
Collector Current - Peak	I <sub>CM</sub>	5.0		Adc
Base Current	I <sub>B</sub>	1.0		Adc
Total Device Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C	P <sub>D</sub>	40 0.32		W W/°C
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-65 to +150		°C
ESD - Human Body Model	НВМ	3B		V
ESD - Machine Model	MM	(		V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

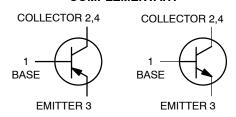
### THERMAL CHARACTERISTICS

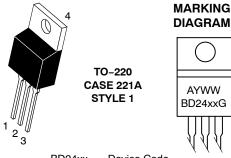
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	62.5	°C/W
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	3.125	°C/W

1

### **POWER TRANSISTORS** COMPLEMENTARY SILICON **3 AMP** 80-100 VOLTS **40 WATTS**

#### **COMPLEMENTARY**





BD24xx = Device Code

xx = 1C, 2B, or 2C

Α = Assembly Location

Year WW Work Week Pb-Free Package

### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
BD241CG	TO-220 (Pb-Free)	50 Units/Rail
BD242CG	TO-220 (Pb-Free)	50 Units/Rail

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

### **DISCONTINUED** (Note 1)

BD242BG	TO-220	50 Units/Rail	
	(Pb-Free)		

**DISCONTINUED:** This device is not recommended for new design. Please contact your onsemi representative for information. The most current information on this device may be available on www.onsemi.com.

<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

### **ELECTRICAL CHARACTERISTICS** (T<sub>C</sub> = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS			•	•	
Collector–Emitter Sustaining Voltage (Note 2) $(I_C = 30 \text{ mAdc}, I_B = 0)$	BD242B BD241C, BD242C	V <sub>CEO</sub>	80 100		Vdc
Collector Cutoff Current $(V_{CE} = 50 \text{ Vdc}, I_B = 0)$ $(V_{CE} = 60 \text{ Vdc}, I_B = 0)$	BD242B BD241C, BD242C	I <sub>CEO</sub>		0.3	mAdc
Collector Cutoff Current $(V_{CE} = 80 \text{ Vdc}, V_{EB} = 0)$ $(V_{CE} = 100 \text{ Vdc}, V_{EB} = 0)$	BD242B BD241C, BD242C	I <sub>CES</sub>		200	μAdc
Emitter Cutoff Current (V <sub>BE</sub> = 5.0 Vdc, I <sub>C</sub> = 0)		I <sub>EBO</sub>		1.0	mAdc
ON CHARACTERISTICS (Note 2)					
DC Current Gain ( $I_C = 1.0$ Adc, $V_{CE} = 4.0$ Vdc) ( $I_C = 3.0$ Adc, $V_{CE} = 4.0$ Vdc)		h <sub>FE</sub>	25 10		
Collector–Emitter Saturation Voltage (I <sub>C</sub> = 3.0 Adc, I <sub>B</sub> = 0.6 Adc)		V <sub>CE(sat)</sub>		1.2	Vdc
Base-Emitter On Voltage (I <sub>C</sub> = 3.0 Adc, V <sub>CE</sub> = 4.0 Vdc)		V <sub>BE(on)</sub>		1.8	Vdc
DYNAMIC CHARACTERISTICS					
Current Gain – Bandwidth Product (Note 3) (I <sub>C</sub> = 500 mAdc, V <sub>CE</sub> = 10 Vdc, f <sub>test</sub> = 1.0 MHz)		f <sub>T</sub>	3.0		MHz
Small-Signal Current Gain (I <sub>C</sub> = 0.5 Adc, V <sub>CE</sub> = 10 Vdc, f = 1.0 kHz)		h <sub>fe</sub>	20		

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

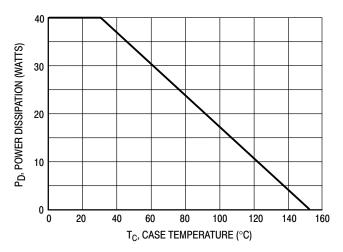


Figure 1. Power Derating

<sup>2.</sup> Pulse Test: Pulse Width  $\leq$  300  $\mu$ s, Duty Cycle  $\leq$  2.0%. 3.  $f_T = |h_{fe}| \bullet f_{test}$ .

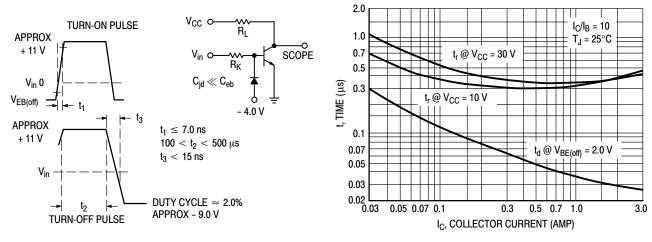


Figure 2. Switching Time Equivalent Circuit

Figure 3. Turn-On Time

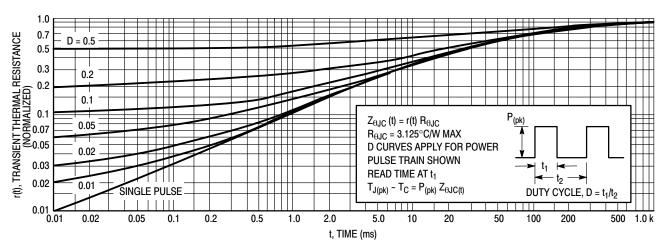


Figure 4. Thermal Response

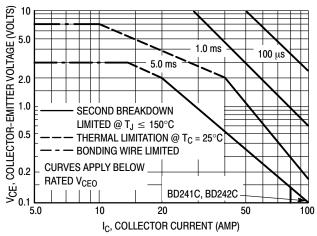


Figure 5. Active Region Safe Operating Area

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate  $I_C$  –  $V_{CE}$  limits of the transistor that must be observed for reliable operation, i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 5 is based on  $T_{J(pk)} = 150^{\circ}\text{C}$ ;  $T_{C}$  is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided  $T_{J(pk)} \leq 150^{\circ}\text{C}$ ,  $T_{J(pk)}$  may be calculated from the data in Figure 4. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

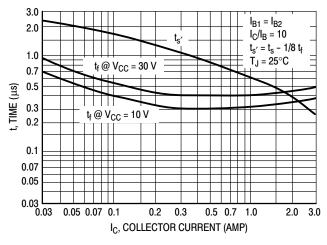


Figure 6. Turn-Off Time

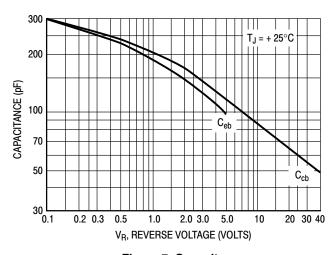


Figure 7. Capacitance

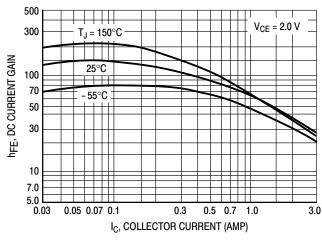


Figure 8. DC Current Gain

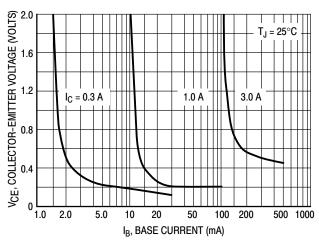


Figure 9. Collector Saturation Region

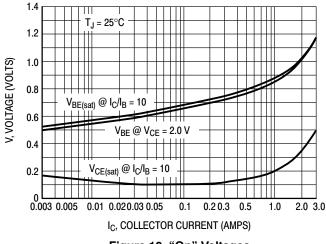


Figure 10. "On" Voltages

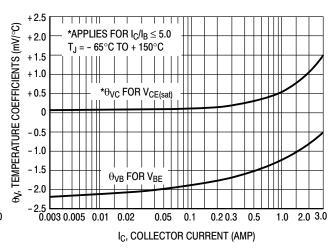
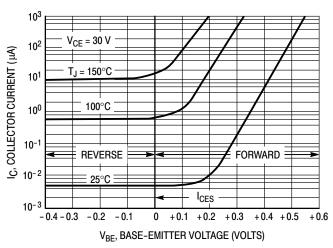


Figure 11. Temperature Coefficients



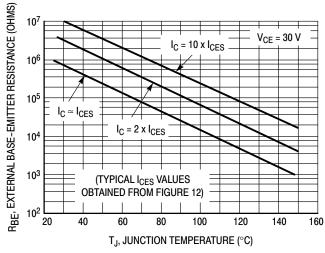


Figure 12. Collector Cut-Off Region

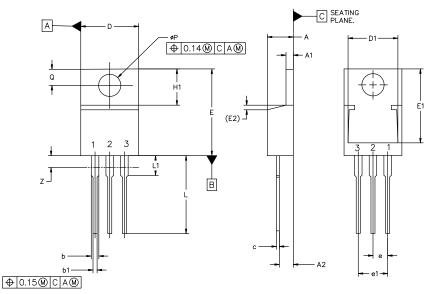
Figure 13. Effects of Base-Emitter Resistance





### TO-220-3 10.10x15.12x4.45, 2.54P CASE 221A **ISSUE AL**

**DATE 05 FEB 2025** 



MILLIMETERS					
DIM	MIN	NOM	MAX		
Α	4.07	4.45	4.83		
A1	1.15	1.28	1.41		
A2	2.04	2.42	2.79		
b	1.15	1.34	1.52		
b1	0.64	0.80	0.96		
С	0.36	0.49	0.61		
D	9.66	10.10	10.53		
D1	8.43	8.63	8.83		
Е	14.48	15.12	15.75		
E1	12.58	12.78	12.98		
E2	1.27 REF				

MILLIMETERS					
DIM	MIN	NOM	MAX		
е	2.42	2.54	2.66		
e1	4.83	5.08	5.33		
H1	5.97	6.22	6.47		
L	L 12.70		14.27		
L1	2.80	3.45	4.10		
Q	2.54	2.79	3.04		
ØΡ	3.60	3.85	4.09		
Z	-,	-,	3.48		

#### NOTES:

- NOTES:

  1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018.

  2. CONTROLLING DIMENSION: MILLIMETERS.

  3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

STYLE 1:		STYLE 2:		STYLE 3:		STYLE 4:	
PIN 1.	BASE	PIN 1.	BASE	PIN 1.	CATHODE	PIN 1.	MAIN TERMINAL 1
2.	COLLECTOR	2.	EMITTER	2.	ANODE	2.	MAIN TERMINAL 2
3.	EMITTER	3.	COLLECTOR	3.	GATE	3.	GATE
4.	COLLECTOR	4.	EMITTER	4.	ANODE	4.	MAIN TERMINAL 2
STYLE 5:		STYLE 6:		STYLE 7:		STYLE 8:	
PIN 1.	GATE	PIN 1.	ANODE	PIN 1.	CATHODE	PIN 1.	CATHODE
2.	DRAIN	2.	CATHODE	2.	ANODE	2.	ANODE
3.	SOURCE	3.	ANODE	3.	CATHODE	3.	EXTERNAL TRIP/DELAY
4.	DRAIN	4.	CATHODE	4.	ANODE	4.	ANODE
STYLE 9:		STYLE 10:		STYLE 11:	:	STYLE 12:	:
PIN 1.	GATE	PIN 1.	GATE	PIN 1.	DRAIN	PIN 1.	MAIN TERMINAL 1
2.	COLLECTOR	2.	SOURCE	2.	SOURCE	2.	MAIN TERMINAL 2
3.	EMITTER	3.	DRAIN	3.	GATE	3.	GATE
4.	COLLECTOR	4.	SOURCE	4.	SOURCE	4.	NOT CONNECTED

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DESCRIPTION:	TO-220-3 10.10x15.12x4.45, 2.54P		PAGE 1 OF 1	

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